

General Purpose Transistors

NPN Silicon

- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: >4000 V
– Machine Model: >400 V
- We declare that the material of product compliance with RoHS requirements.

MAXIMUM RATINGS

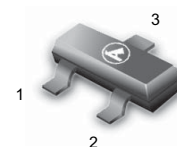
Rating	Symbol	Value	Unit
Collector–Emitter Voltage LBC846 LBC847, LBC850 LBC848, LBC849	V_{CEO}	65 45 30	Vdc
Collector–Base Voltage LBC846 LBC847, LBC850 LBC848, LBC849	V_{CBO}	80 50 30	Vdc
Emitter–Base Voltage LBC846 LBC847, LBC850 LBC848, LBC849	V_{EBO}	6.0 6.0 5.0	Vdc
Collector Current – Continuous	I_C	100	mAdc

THERMAL CHARACTERISTICS

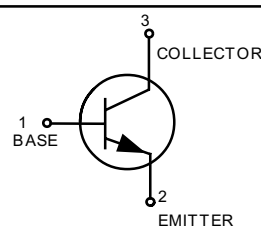
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board (Note 1.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient (Note 1.)	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate (Note 2.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient (Note 2.)	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

1. FR–5 = 1.0 x 0.75 x 0.062 in
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

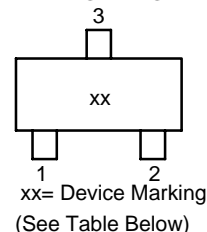
LBC846ALT1G Series



SOT–23



MARKING DIAGRAM



LBC846ALT1G Series**DEVICE MARKING AND ORDERING INFORMATION**

Device	Marking	Package	Shipping
LBC846ALT1G	1A	SOT-23	3000/Tape&Reel
LBC846ALT3G	1A	SOT-23	10000/Tape&Reel
LBC846BLT1G	1B	SOT-23	3000/Tape&Reel
LBC846BLT3G	1B	SOT-23	10000/Tape&Reel
LBC847ALT1G	1E	SOT-23	3000/Tape&Reel
LBC847ALT3G	1E	SOT-23	10000/Tape&Reel
LBC847BLT1G	1F	SOT-23	3000/Tape&Reel
LBC847BLT3G	1F	SOT-23	10000/Tape&Reel
LBC847CLT1G	1G	SOT-23	3000/Tape&Reel
LBC847CLT3G	1G	SOT-23	10000/Tape&Reel
LBC848ALT1G	1J	SOT-23	3000/Tape&Reel
LBC848ALT3G	1J	SOT-23	10000/Tape&Reel
LBC848BLT1G	1K	SOT-23	3000/Tape&Reel
LBC848BLT3G	1K	SOT-23	10000/Tape&Reel
LBC848CLT1G	1L	SOT-23	3000/Tape&Reel
LBC848CLT3G	1L	SOT-23	10000/Tape&Reel
LBC849BLT1G	2B	SOT-23	3000/Tape&Reel
LBC849BLT3G	2B	SOT-23	10000/Tape&Reel
LBC849CLT1G	2C	SOT-23	3000/Tape&Reel
LBC849CLT3G	2C	SOT-23	10000/Tape&Reel
LBC850BLT1G	2F	SOT-23	3000/Tape&Reel
LBC850BLT3G	2F	SOT-23	10000/Tape&Reel
LBC850CLT1G	2G	SOT-23	3000/Tape&Reel
LBC850CLT3G	2G	SOT-23	10000/Tape&Reel

LBC846ALT1G Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage ($I_C = 10\text{ mA}$)	LBC846A,B LBC847A,B,C, LBC850B,C LBC848A,B,C, LBC849B,C	$V_{(BR)CEO}$	65 45 30	– – –	– – –	V
Collector–Emitter Breakdown Voltage ($I_C = 10\text{ }\mu\text{A}$, $V_{EB} = 0$)	LBC846A,B LBC847A,B,C, LBC850B,C LBC848A,B,C, LBC849B,C	$V_{(BR)CES}$	80 50 30	– – –	– – –	V
Collector–Base Breakdown Voltage ($I_C = 10\text{ }\mu\text{A}$)	LBC846A,B LBC847A,B,C, LBC850B,C LBC848A,B,C, LBC849B,C	$V_{(BR)CBO}$	80 50 30	– – –	– – –	V
Emitter–Base Breakdown Voltage ($I_E = 1.0\text{ }\mu\text{A}$)	LBC846A,B LBC847A,B,C, LBC850B,C LBC848A,B,C, LBC849B,C	$V_{(BR)EBO}$	6.0 6.0 5.0	– – –	– – –	V
Collector Cutoff Current ($V_{CB} = 30\text{ V}$) ($V_{CB} = 30\text{ V}$, $T_A = 150^\circ\text{C}$)		I_{CBO}	– –	– –	15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain ($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$)	LBC846A, LBC847A, LBC848A LBC846B, LBC847B, LBC848B, LBC849B, LBC850B LBC847C, LBC848C, LBC849C, LBC850C	h_{FE}	110 200 420	180 290 520	220 450 800	–
Collector–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)		$V_{CE(sat)}$	– –	– –	0.25 0.6	V
Base–Emitter Saturation Voltage ($I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$) ($I_C = 100\text{ mA}$, $I_B = 5.0\text{ mA}$)		$V_{BE(sat)}$	– –	0.7 0.9	– –	V
Base–Emitter Voltage ($I_C = 2.0\text{ mA}$, $V_{CE} = 5.0\text{ V}$) ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ V}$)		$V_{BE(on)}$	580 –	660 –	700 770	mV
SMALL–SIGNAL CHARACTERISTICS						
Current–Gain – Bandwidth Product ($I_C = 10\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $f = 100\text{ MHz}$)		f_T	100	–	–	MHz
Output Capacitance ($V_{CB} = 10\text{ V}$, $f = 1.0\text{ MHz}$)		C_{obo}	–	–	4.5	pF
Noise Figure ($I_C = 0.2\text{ mA}$, $V_{CE} = 5.0\text{ Vdc}$, $R_S = 2.0\text{ k}\Omega$, $f = 1.0\text{ kHz}$, $BW = 200\text{ Hz}$)	LBC846A,B, LBC847A,B,C, LBC848A,B,C LBC849B,C, LBC850B,C	NF	– –	– –	10 4.0	dB

LBC846ALT1G Series

LBC846A, LBC847A, LBC848A

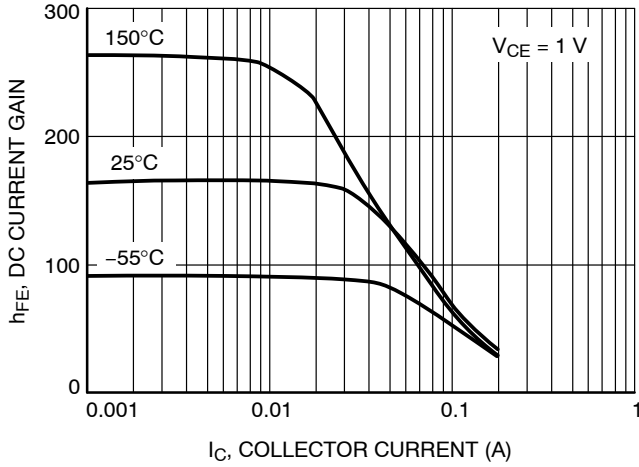


Figure 1. DC Current Gain vs. Collector Current

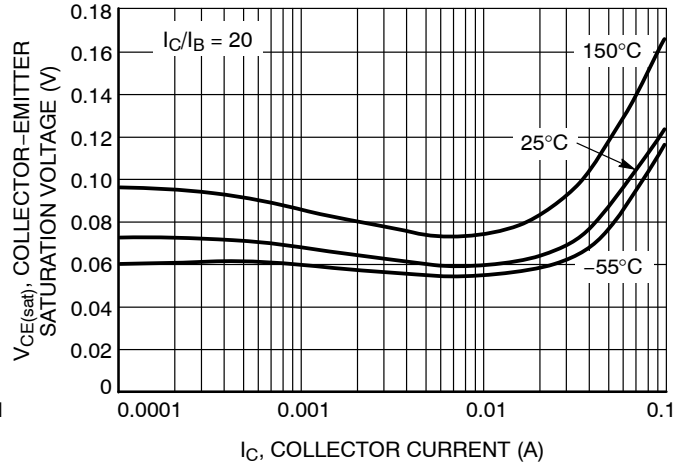


Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

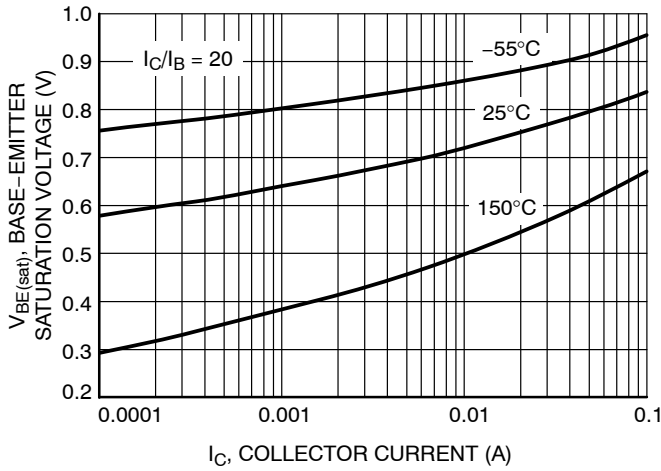


Figure 3. Base Emitter Saturation Voltage vs. Collector Current

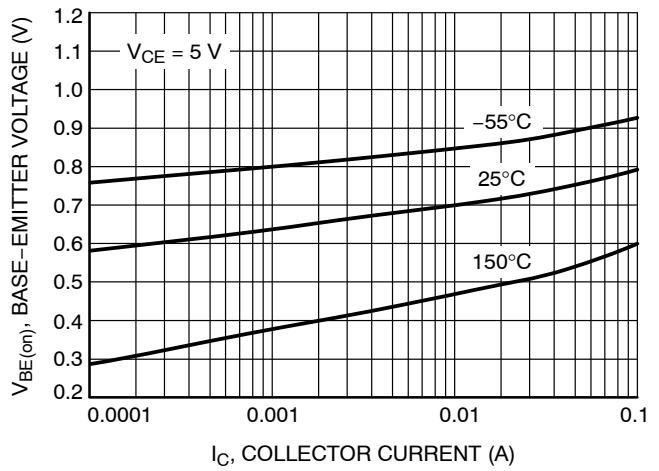


Figure 4. Base Emitter Voltage vs. Collector Current

LBC846ALT1G Series

LBC846A, LBC847A, LBC848A

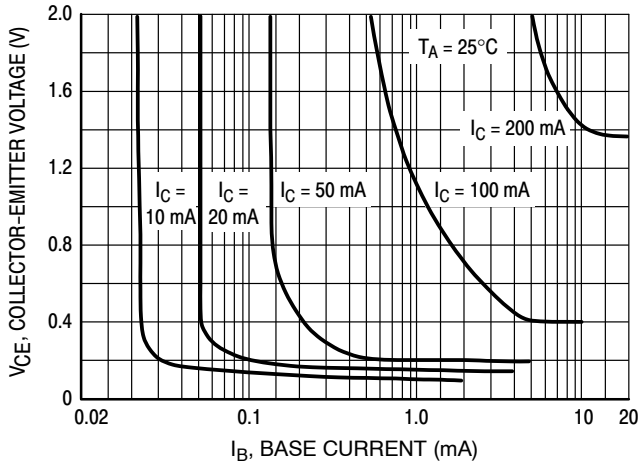


Figure 5. Collector Saturation Region

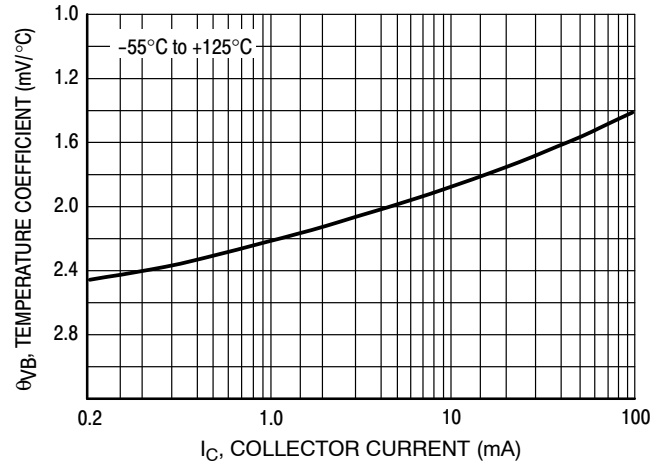


Figure 6. Base-Emitter Temperature Coefficient

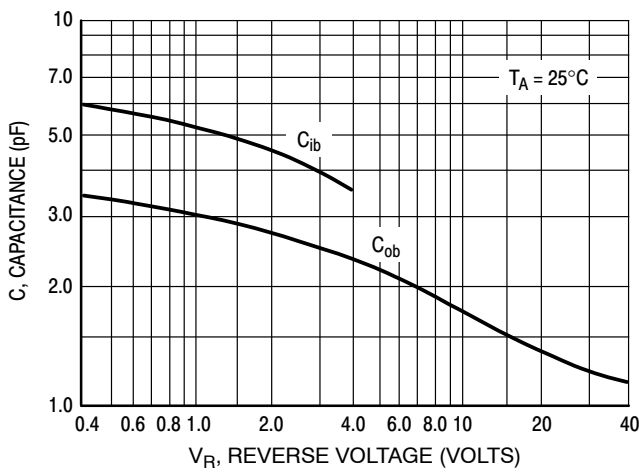


Figure 7. Capacitances

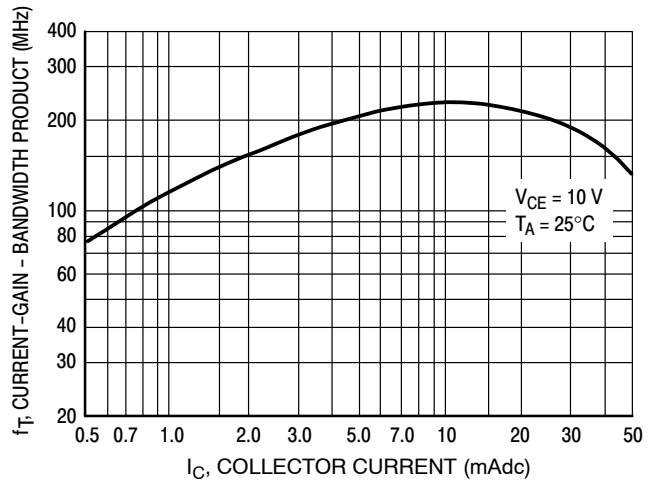


Figure 8. Current-Gain - Bandwidth Product

LBC846ALT1G Series

LBC846B

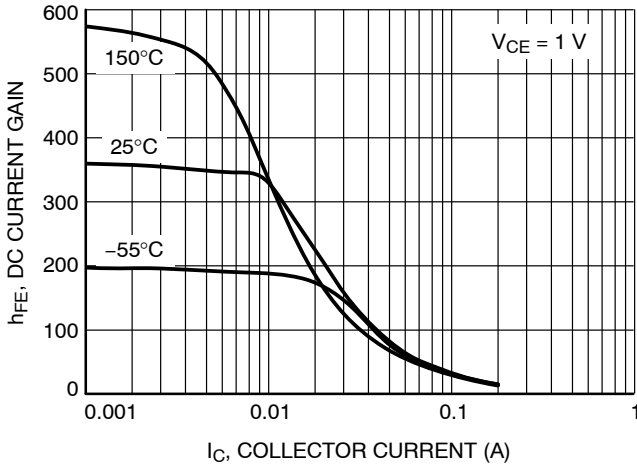


Figure 9. DC Current Gain vs. Collector Current

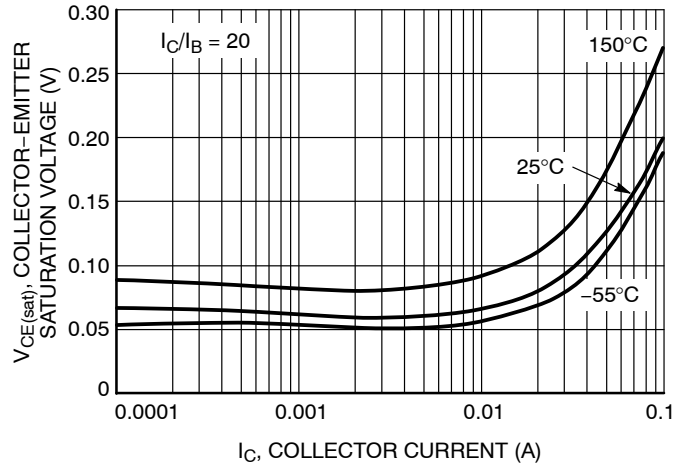


Figure 10. Collector Emitter Saturation Voltage vs. Collector Current

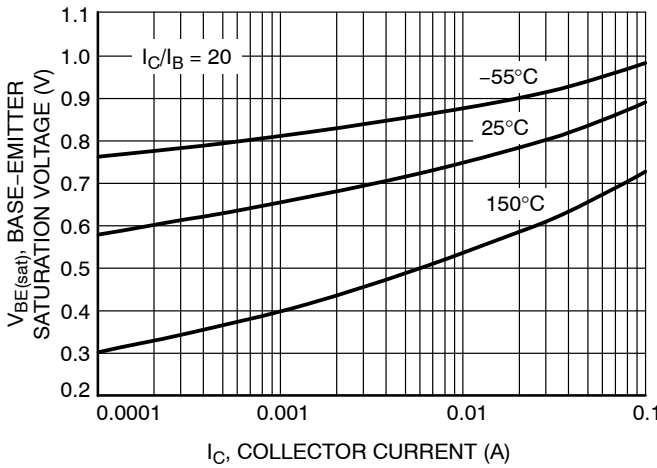


Figure 11. Base Emitter Saturation Voltage vs. Collector Current

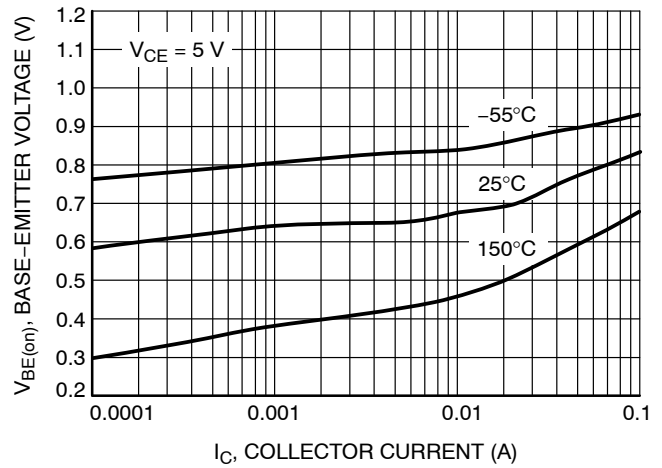


Figure 12. Base Emitter Voltage vs. Collector Current

LBC846ALT1G Series

LBC846B

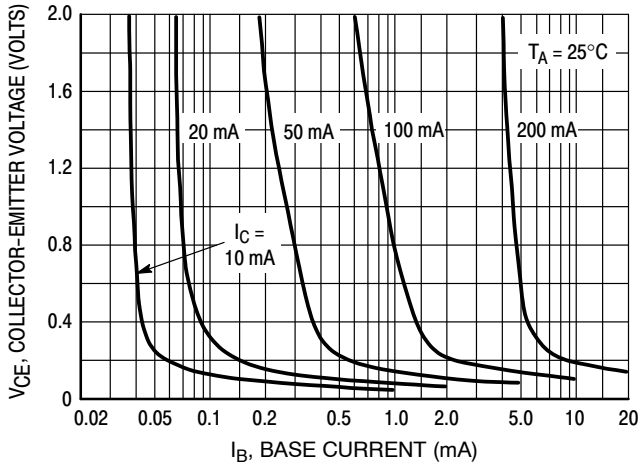


Figure 13. Collector Saturation Region

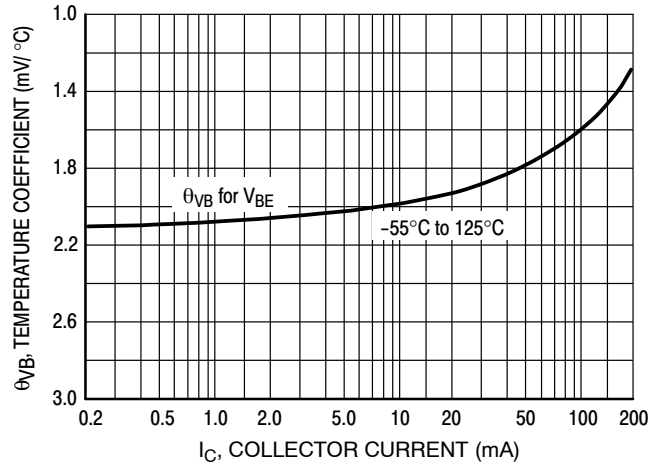


Figure 14. Base-Emitter Temperature Coefficient

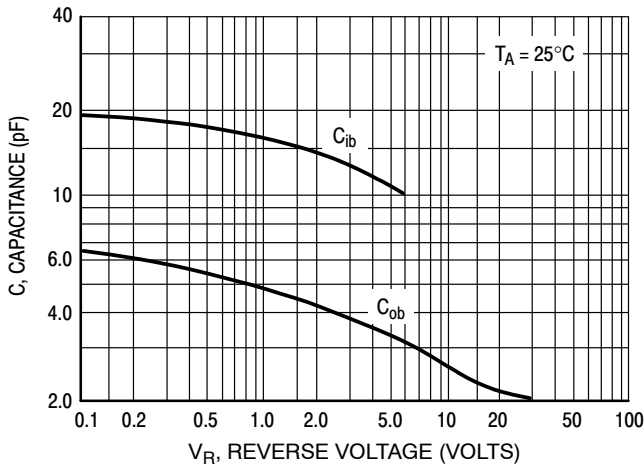


Figure 15. Capacitance

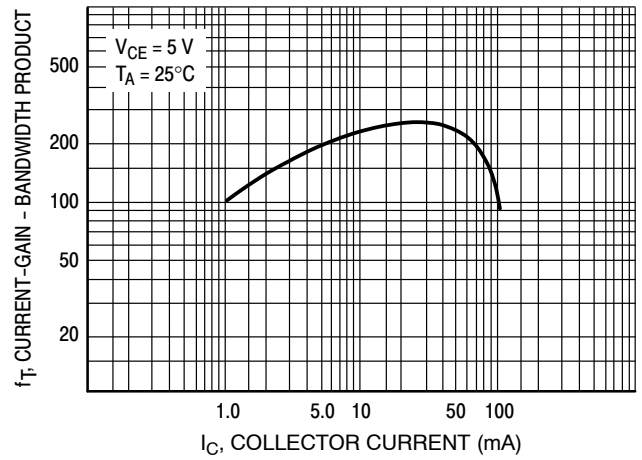


Figure 16. Current-Gain - Bandwidth Product

LBC846ALT1G Series

LBC847B, LBC848B, LBC849B, LBC850B

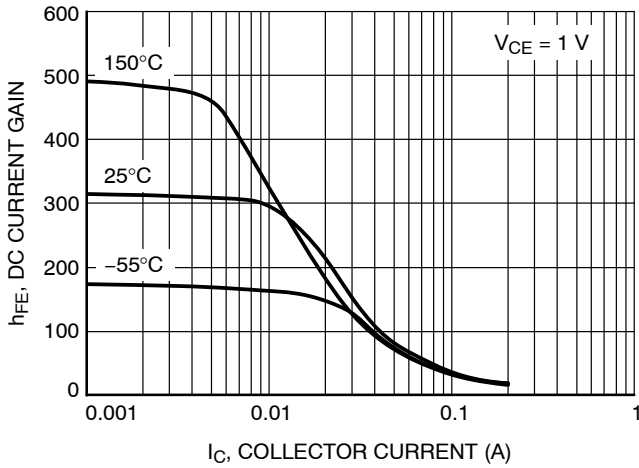


Figure 17. DC Current Gain vs. Collector Current

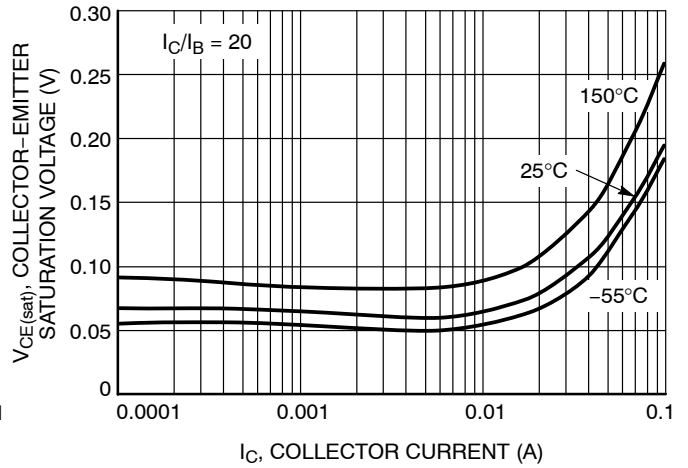


Figure 18. Collector Emitter Saturation Voltage vs. Collector Current

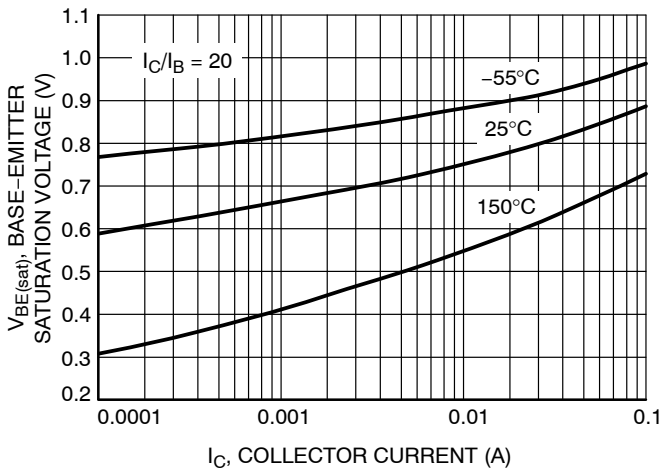


Figure 19. Base Emitter Saturation Voltage vs. Collector Current

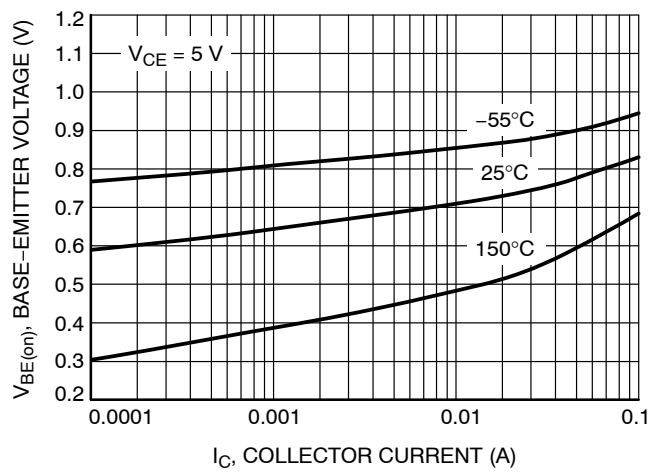
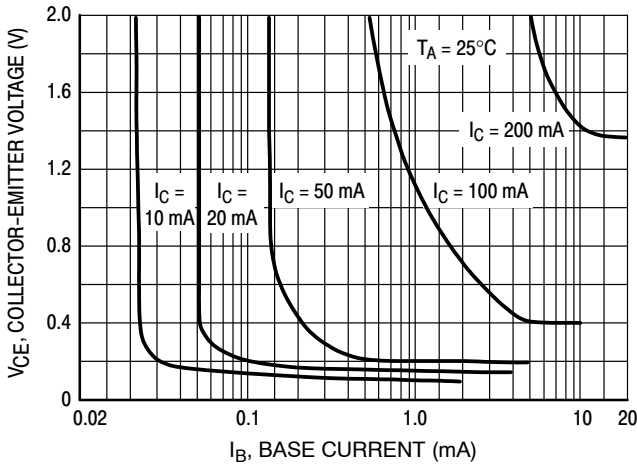
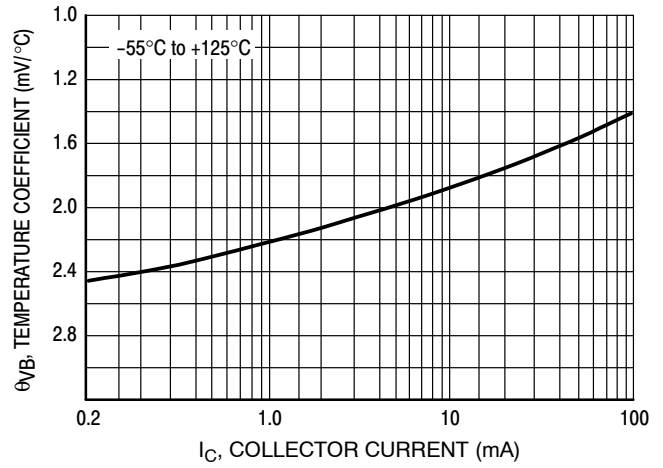
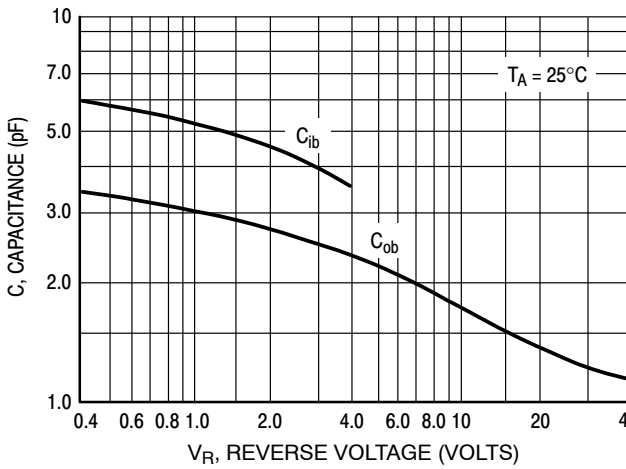
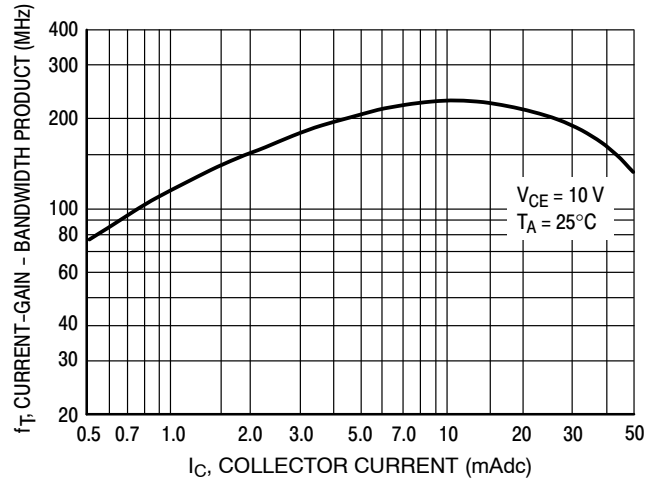


Figure 20. Base Emitter Voltage vs. Collector Current

LBC846ALT1G Series
LBC847B, LBC848B, LBC849B, LBC850B

Figure 21. Collector Saturation Region

Figure 22. Base-Emitter Temperature Coefficient

Figure 23. Capacitances

Figure 24. Current-Gain - Bandwidth Product

LBC846ALT1G Series

LBC847C, LBC848C, LBC849C, LBC850C

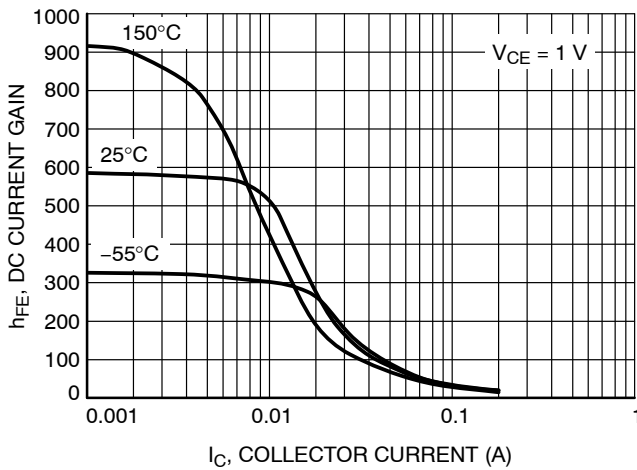


Figure 25. DC Current Gain vs. Collector Current

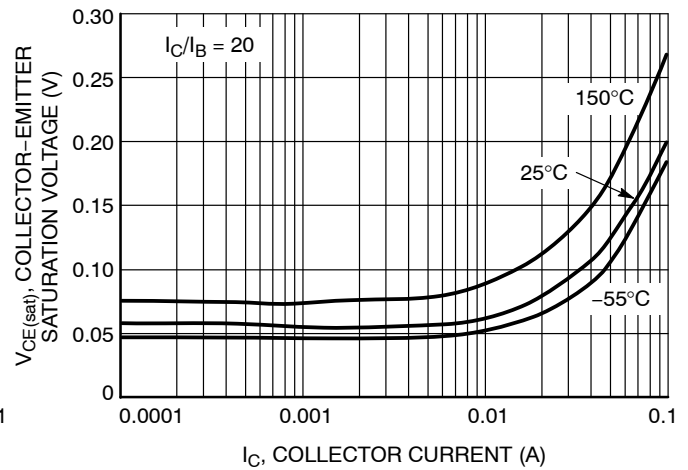


Figure 26. Collector Emitter Saturation Voltage vs. Collector Current

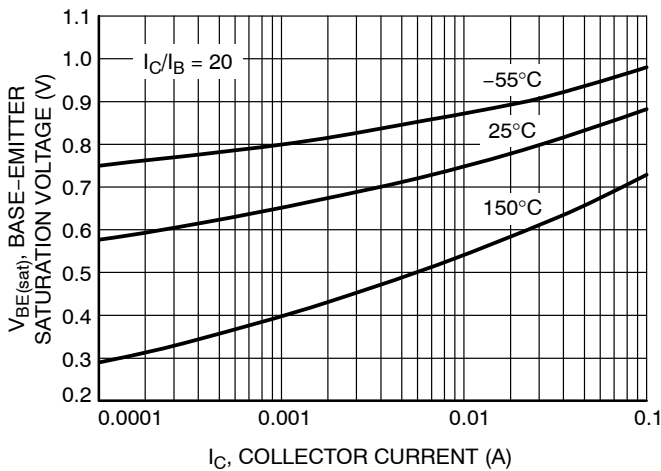


Figure 27. Base Emitter Saturation Voltage vs. Collector Current

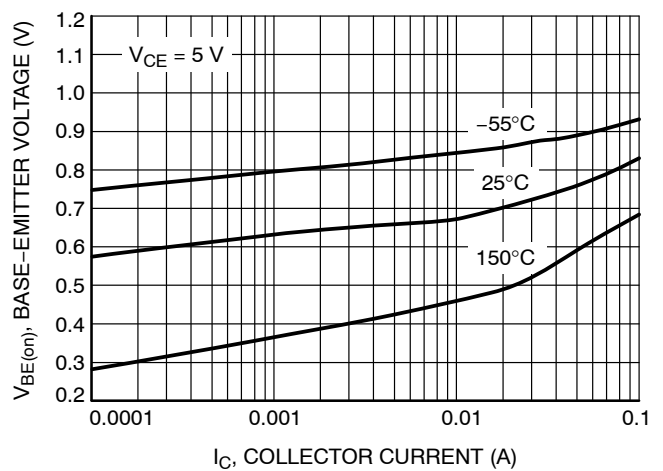


Figure 28. Base Emitter Voltage vs. Collector Current

LBC846ALT1G Series

LBC847C, LBC848C, LBC849C, LBC850C

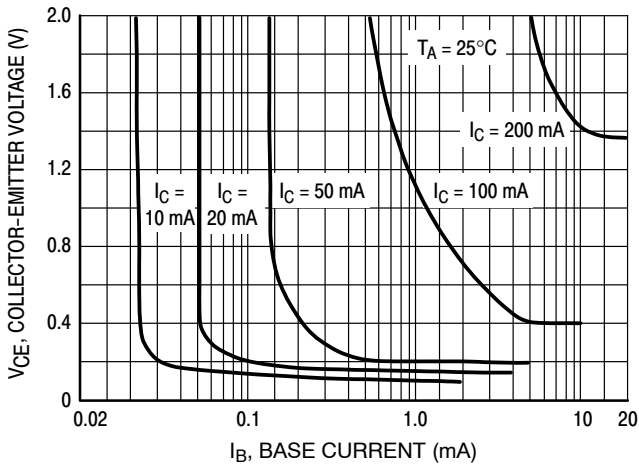


Figure 29. Collector Saturation Region

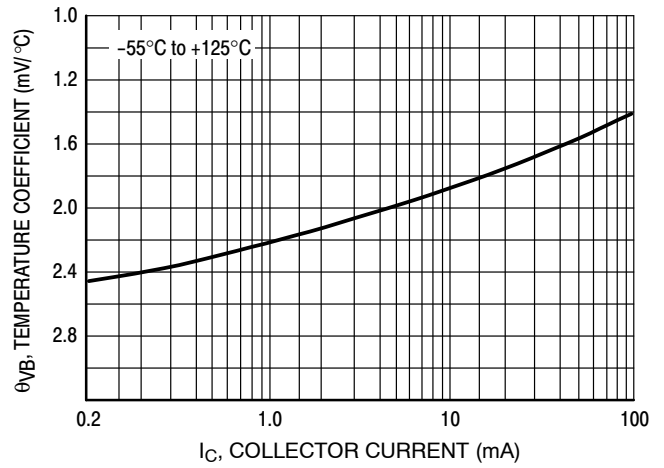


Figure 30. Base-Emitter Temperature Coefficient

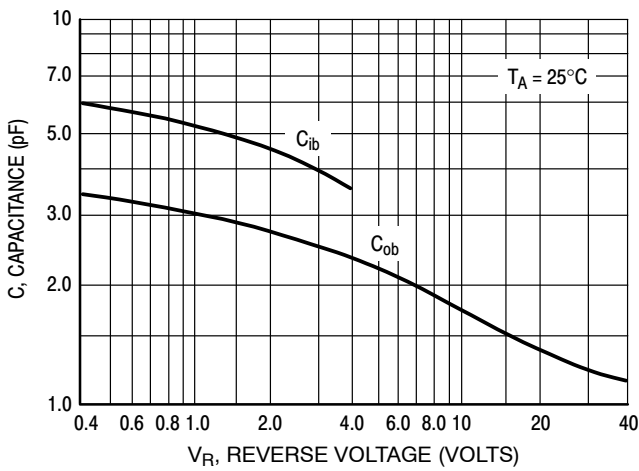


Figure 31. Capacitances

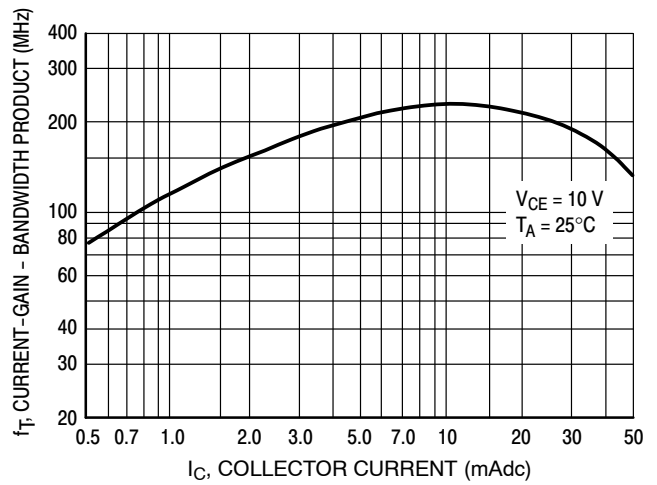
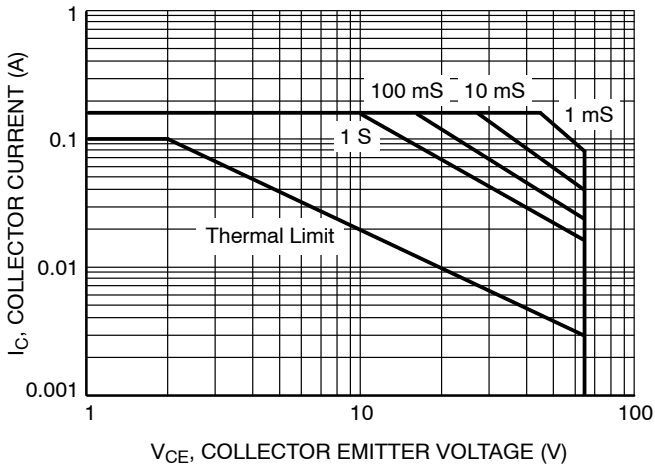
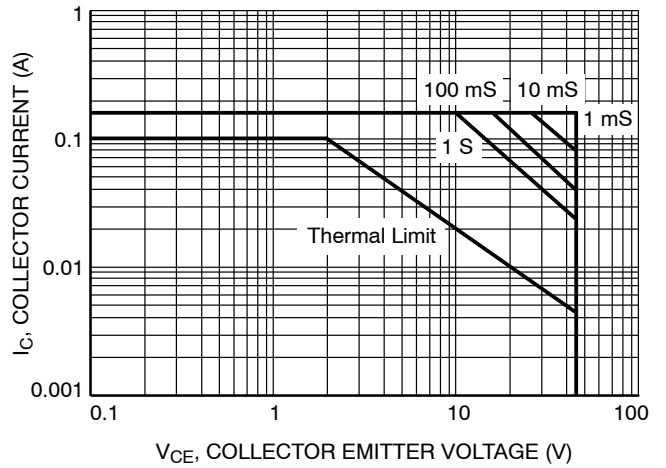


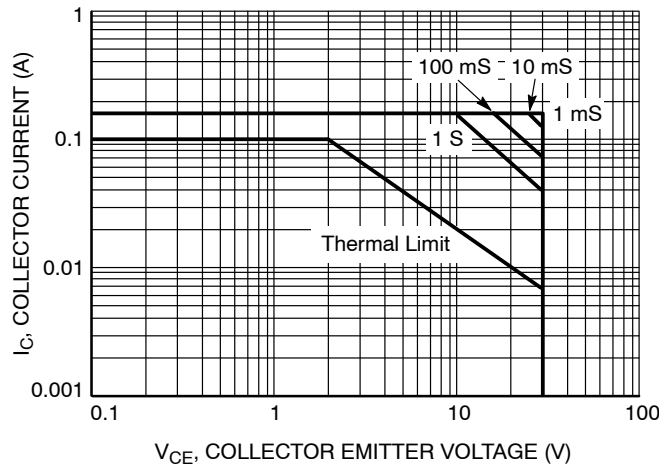
Figure 32. Current-Gain - Bandwidth Product

LBC846ALT1G Series


**Figure 33. Safe Operating Area for
LBC846A, LBC846B**



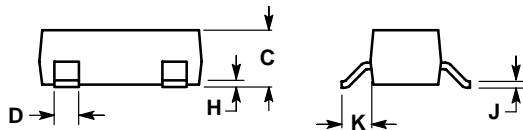
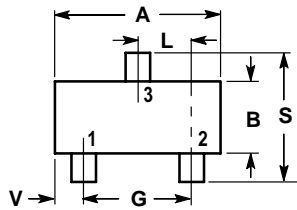
**Figure 34. Safe Operating Area for
LBC847A, LBC847B, LBC847C, LBC850B, LBC850C**



**Figure 35. Safe Operating Area for
LBC848A, LBC848B, LBC848C, LBC849B, LBC849C**

LBC846ALT1G Series

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

